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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/822,361	04/12/2004	Ilya Karpov	ITL.0835D1US (P14730D)	3077
75	90 09/12/2005		EXAMI	NER
Trop, Pruner & Hu, P.C.			PHAM, LONG	
Suite 100 8554 Katy Freeway		ART UNIT	PAPER NUMBER	
Houston, TX			2814	
			DATE MAILED: 09/12/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	10/822,361	KARPOV ET AL.				
Office Action Summary	Examiner	Art Unit				
	Long Pham	2814				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).				
Status						
Responsive to communication(s) filed on This action is FINAL. 2b)⊠ This Since this application is in condition for allowan closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro					
Disposition of Claims		,				
4) ☐ Claim(s) 10,11 and 16-18 is/are pending in the 4a) Of the above claim(s) is/are withdraw 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 10, 11, and 16-18 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or	vn from consideration.					
Application Papers	·					
9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access applicant may not request that any objection to the or Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Examiner 9) The specification is objected to by the Examiner 10) The oath or declaration is objected to by the Examiner 11)	epted or b) objected to by the Idrawing(s) be held in abeyance. See ion is required if the drawing(s) is object.	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau * See the attached detailed Office action for a list of	s have been received. s have been received in Applicati ity documents have been receive ı (PCT Rule 17.2(a)).	on No ed in this National Stage				
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Do 5) Notice of Informal P 6) Other:					

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

1. Claims 10 and 16 are rejected under 35 U.S.C. 102(e) as being anticipated by Nishida et al. (US patent 6,461,934).

With respect to claim 10, Nishida et al. teach an integrated circuit comprising (see figs. 1-5 and associated text):

a semiconductor structure;

a first trench 103b formed of a first depth in said semiconductor structure; a covering 106 on said first trench and over said semiconductor structure, said covering being thicker in said first trench than over said semiconductor structure; and

said covering having an opening through said covering to define a region for a second trench.

With respect to claim 16, Nishida et al. further teach the opening is a second trench. See figs. 1-5.

Claim Rejections - 35 USC § 103

2. Claims 11, 17, and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishida et al. (US patent 6,461,934) in combination with Wen et al. (US patent 5,460,987).

With respect to claim 11, Nishida et al. fail to teach that the covering is made of spin-on-glass material.

However, the use of spin-on-glass as covering material is well-known in the art.

With respect to claims 17 and 18, Nishida et al. fail to teach that opening for forming a second trench extends transversely or the opening for forming the

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second trench crosses the first trench and the second trench is shallower than the first trench.

Wen et al. teach forming a second trench crossing a first trench and the second trench is shallower than the first trench. See figs. 1-8 and associated text.

It would have been obvious to one of <u>ordinary skill</u> in the art of making semiconductor devices incorporate the above teaching of Wen et al. into the device of Nishida et al. to reduce leakage current for the structure. See the abstract.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Long Pham whose telephone number is 571-272-1714. The examiner can normally be reached on M-F, 7:30AM-3:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair.direct.uspto.gov. Should you have questions on access to the Private PAIR system contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Long Pham

Primary Examiner

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